

Continental Device India Limited

An ISO/TS 16949, ISO 9001 and ISO 14001 Certified Company





NPN SILICON PLANAR EPITAXIAL TRANSISTORS



2N3700 2N3701 TO-18

General purpose amplifier

ABSOLUTE MAXIMUM RATINGS.

| DESCRIPTION | SYMBOL | VALUE | UNIT |
|--------------------------------|----------|-------------|----------|
| Collector -Base Voltage | VCBO | 140 | V |
| Collector -Emitter Voltage | VCEO | 80 | V |
| Emitter -Base Voltage | VEBO | 7.0 | V |
| Collector Current | IC | 1.0 | Α |
| Power Dissipation @Ta=25 deg C | PD | 500 | mW |
| Derate Above 25 deg C | | 2.85 | mW/deg C |
| @TC=25 deg C | PD | 1.8 | W |
| Derate Above 25 deg C | | 10.6 | mW/deg C |
| Operating And Storage Junction | Tj, Tstg | -65 to +200 | deg C |
| Temperature Range | | | |
| THERMAL RESISTANCE | | | |
| Junction to Case | Rth(j-c) | 70 | deg C/W |
| Junction to Ambient | Rth(j-a) | 245 | deg C/W |

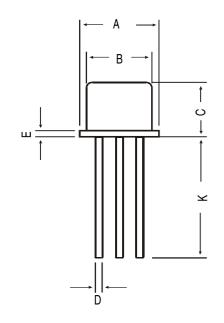
| Carlotton to / timbiont | ι και (j ω) | | 2-10 | | acg c/ vv | | | |
|---|-------------|------------------|---------|--------|-----------|--|--|--|
| ELECTRICAL CHARACTERISTICS (Ta=25 deg C Unless Otherwise Specified) | | | | | | | | |
| DESCRIPTION | SYMBOL | TEST CONDITION | MIN | MAX | UNIT | | | |
| Collector-Cut off Current | ICBO | VCB=90V, IE=0 | - | 10 | nA | | | |
| | | | | | | | | |
| | | | | | | | | |
| | | VCB=90V, IE=0 | - | 10 | uA | | | |
| Emitter-Cut off Current | IEBO | VEB=5V, IC=0 | - | 10 | nA | | | |
| Collector -Base Voltage | VCBO | IC=100uA, IE=-0 | 140 | - | V | | | |
| Collector -Emitter Voltage | VCEO* | IC=30mA, IB=0 | 80 | - | V | | | |
| Emitter -Base Voltage | VEBO | IE=100uA, IC=-0 | 7.0 | - | V | | | |
| Collector Emitter (Sat) Voltage | VCE(Sat)* | IC=150mA,IB=15mA | - | 0.2 | V | | | |
| | | IC=500mA,IB=50mA | - | 0.5 | V | | | |
| Base Emitter (Sat) Voltage | VBE(Sat) * | IC=150mA,IB=15mA | - | 1.1 | V | | | |
| | | | 2N3700 | 2N3701 | | | | |
| DC Current Gain | hFE* | IC=0.1mA,VCE=10V | >50 | 30-100 | | | | |
| | | IC=10mA,VCE=10V | >90 | 40-120 | | | | |
| | | IC=150mA,VCE=10V | 100-300 | 40-120 | | | | |
| | | IC=500mA,VCE=10V | >50 | 30-100 | | | | |
| | | IC=1A,VCE=10V | >15 | >15 | | | | |
| | | Tc= -55 deg C | | | | | | |
| | | IC=150mA,VCE=10V | >40 | - | | | | |

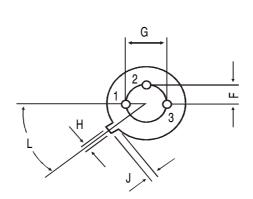
| ELECTRICAL CHARACTERISTICS | Ta=25 deg | C Unless | Otherwise Specified | 2N3700-0 |
|-----------------------------------|------------|----------|---------------------|---------------------|
| LEEGINICAL CHANACTENISTICS | I a-25 ucq | o omess | Other wise opecined | / <u>2113700-</u> 0 |

| DESCRIPTION | CRIPTION SYMBOL TEST CONDITION | | MIN | MAX | UNIT | |
|------------------------------|--------------------------------|--|---------|--------|------|--|
| Dynamic Characteristics | | | 2N3700 | 2N3701 | | |
| Small Signal Current Gain | hfe | IC=1mA, VCE=5V f=1KHz | 80-400 | 30-200 | | |
| Transition Frequency | ft | VCE=10V,IC=50mA, f=20MHz | 100-400 | >80 | MHz | |
| Input Capacitance | Cibo | | <60 | <60 | pF | |
| Output Capacitance | Cobo | VCB=10V, f=1MHz | <12 | <12 | pF | |
| Collector Base Time Constant | rbb'cb'c | f=79.8MHz | 15-400 | 25-400 | ps | |
| Noise Figure | NF | VCE=10V, IC=100uA RS=1kohms, f=1kHz | - | 4.0 | dB | |

^{*}Pulse Test: Pulse Width =300us, Duty Cycle=1%

TO-18 Metal Can Package





| λ X 4 | | | | |
|----------|--|--|--|--|
| 4 | | | | |
| • | | | | |
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| 3 | | | | |
| 3 | | | | |
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| 1 | | | | |
| | | | | |
| 45 DEG | | | | |
| | | | | |



PIN CONFIGURATION

- 1. EMITTER
- BASE
- COLLECTOR

Packing Detail

| PACKAGE | STANDARD PACK | | INNER CARTON BOX | | OUTER CARTON BOX | | |
|---------|---------------|----------------|------------------|------|-------------------|-------|--------|
| | Details | Net Weight/Qty | Size | Qty | Size | Qty | Gr Wt |
| T0-18 | 1K/polybag | 350 gm/1K pcs | 3" x 7.5" x 7.5" | 5.0K | 17" x 15" x 13.5" | 80.0K | 34 kgs |

Notes

Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Discrete Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished on the CDIL Web Site/CD is believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

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